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JAN 26 2006

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE  
BEFORE THE BOARD OF PATENT APPEALS AND INTERFERENCES

Date : 1/26/2006  
IN RE APPLICATION OF: Alan R. Ball et al.  
APPLN. NO. : 10/813501  
FILED : 3/31/2004  
FOR : METHOD OF FORMING A SELF-GATED  
TRANSISTOR AND STRUCTURE THEREFOR  
EXAMINER : Quan Tra  
Phone : 571-272-1755  
Group : 2816

I HEREBY CERTIFY THAT THIS CORRESPONDENCE IS BEING FACSIMILE  
TRANSMITTED TO THE PATENT AND TRADEMARK OFFICE,  
ATTN EXAMINER Quan Tra  
AT THE FAX NO. 571-273-8300  
ON: 1/26/2006 (Date of Facsimile Transmission)

by: Lydia McNamara (Name of Person Signing Certificate)

*Lydia McNamara*  
SIGNATURE

1/26/2006  
DATE

NOTICE OF APPEAL TO THE  
BOARD OF PATENT APPEALS AND INTERFERENCES

Commissioner for Patents  
P.O. Box 1450  
Alexandria, Virginia 22313-1450

SIR:

In accordance with 37 CFR 41.31, applicants hereby appeal to the Board of Patent Appeals and Interferences from the final rejection by the Examiner of claims 1-20.

Please charge the cost of the Appeal (\$500.00) to Deposit Account No. 50-1086.

Respectfully submitted,  
Alan R. Ball et al.

*Robert F. Hightower*

01/27/2006 KBETEMA1 00000041 501086 10813501  
Sai. Ref. 00000041 Date 501086 10813501

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